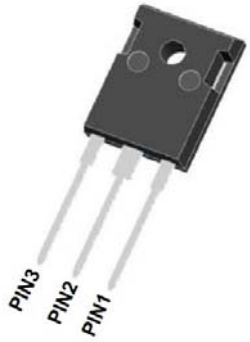
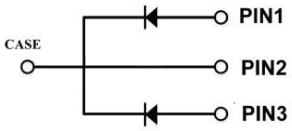
Silicon Carbide Schottky Diode

V_{RRM}	1200V
$I_{F(135°C)}$	46A[2]
Q_C	192nC[2]





Features

- Positive temperature coefficient
- Temperature-independent switching
- Maximum working temperature at 175 °C
- Unipolar devices and zero reverse recovery current
- Zero forward recovery current
- Essentially no switching losses
- Reduction of heat sink requirements
- High-frequency operation
- Reduction of EMI

Typical Applications

Typical applications are in power factor correction(PFC), solar inverter, uninterruptible power supply, motor drives, photovoltaic inverter, electric car and charger.

Mechanical Data

- **Package**: TO-247AB
  Molding compound meets UL 94 V-0 flammability rating, RoHS-compliant, halogen-free
- **Terminals**: Tin plated leads
- **Polarity**: As marked

■Maximum Ratings (T_C=25℃ Unless otherwise specified)

PARAMETER	SYMBOL	UNIT	VALUE
Device marking code			D112030NCTQG3
Reverse voltage (Repetitive peak) @ T_j=25°C	V_{RRM}	V	1200
Reverse voltage (Surge peak) @ T_j=25°C	V_{RSM}	V	1200
Reverse voltage (DC) @ T_j=25°C	V_{DC}	V	1200
Continuous forward current @ T_C=25°C	I_F	A	49/98
Continuous forward current @ T_C=135°C			23/46
Continuous forward current @ T_C=155°C			15/30
Non-repetitive peak forward surge current @ T_C=25°C, tp=10ms, Half Sine Wave	I_{FSM}	A	160[1]
Repetitive peak forward surge current @ T_C=25°C, tp=10ms, Half Sine Wave	I_{FRM}	A	92[1]
Power Dissipation@ T_C=25°C	P_{TOT}	W	214[1]
Power Dissipation@ T_C=110°C			92[1]
i^2t Value@ T_C=25°C ,tp=10ms	$\int i^2dt$	A^2S	128[1]
Operating junction and Storage temperature range	T_j ,T_{stg}	°C	-55 to +175

[1] Per Leg, [2] Per Device

■Electrical Characteristics (Per Leg)

PARAMETER	SYMBOL	UNIT	TEST CONDITIONS	Typ.	Max.
Forward voltage drop	V_F	V	I_F=15A, T_j=25°C	1.35	1.55
			I_F=15A, T_j=175°C	1.85	-
Reverse leakage current	I_R	μA	V_R=1200V, T_j=25°C	3	20
			V_R=1200V, T_j=175°C	19	-
Total capacitive charge	Q_C	nC	V_R=800V, T_j=25°C , $Q_C=\int_0^{VR} C(V)dV$	96	-
Total capacitance	C	pF	V_R=0V, f=1MHZ	1346	-
			V_R=400V, f=1MHZ	90	-
			V_R=800V, f=1MHZ	65	-
Capacitance Stored Energy	E_C	μJ	V_R=800V	25	-

■Thermal Characteristics (Ta=25℃ Unless otherwise specified)

PARAMETER	SYMBOL	UNIT	VALUE
Thermal resistance	$R_{\theta J-C}$	°C /W	0.70(1) 0.35(2)

(1) Per Leg, (2) Per Device

■Typical Characteristics (Per Leg)

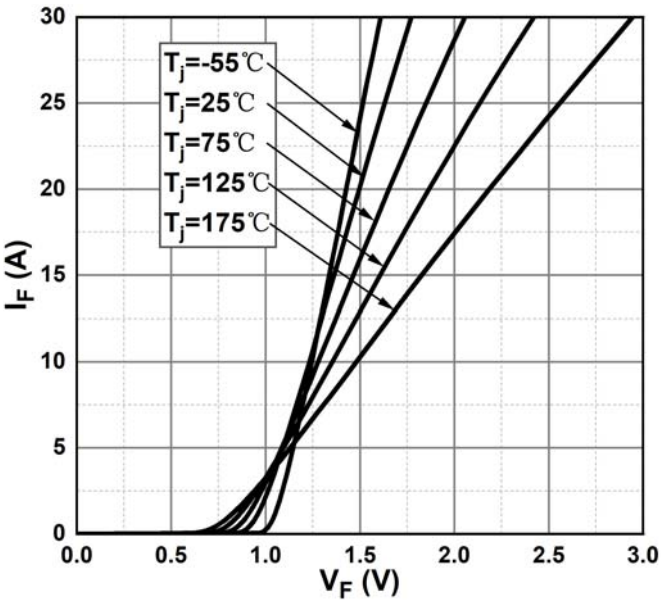


Figure 1. Forward Characteristics

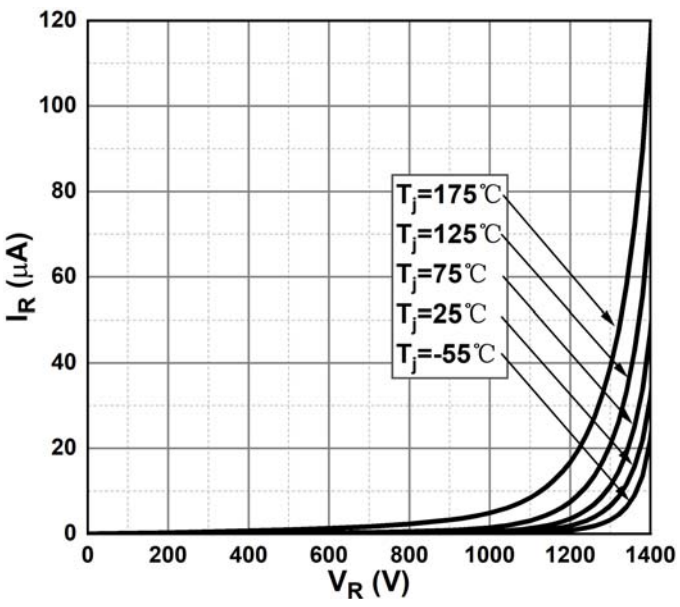


Figure 2. Reverse Characteristics

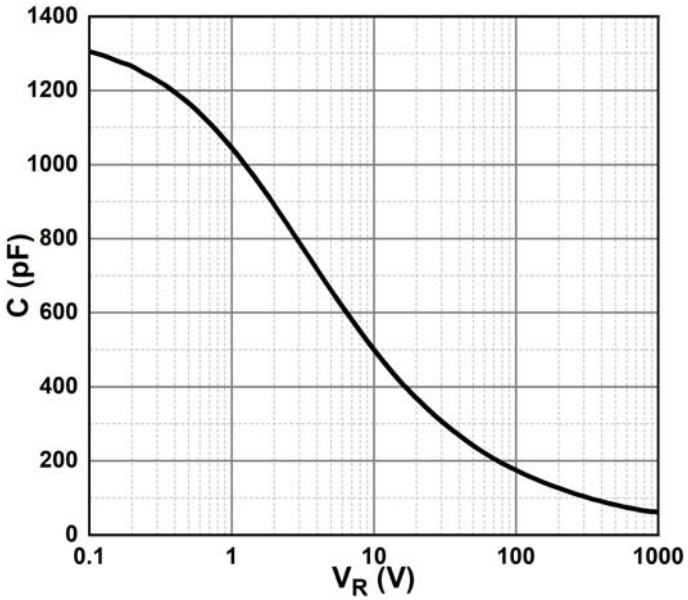


Figure 3. Capacitance vs. Reverse Voltage

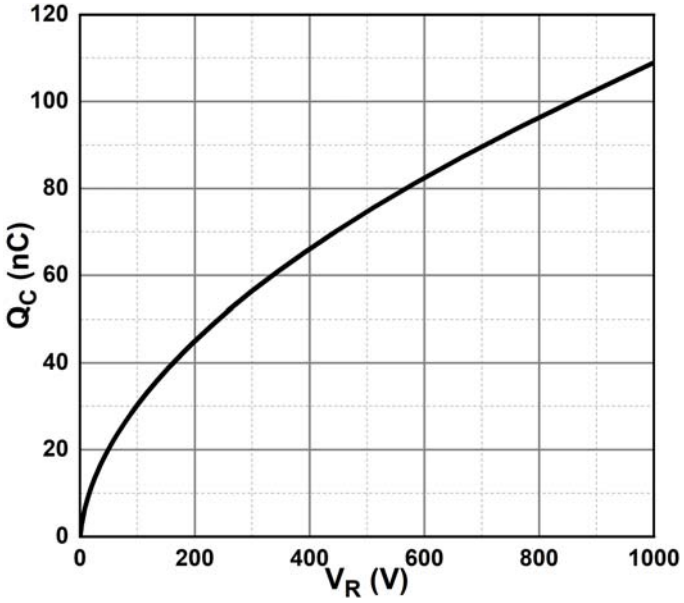


Figure 4. Total Capacitance Charge vs. Reverse Voltage

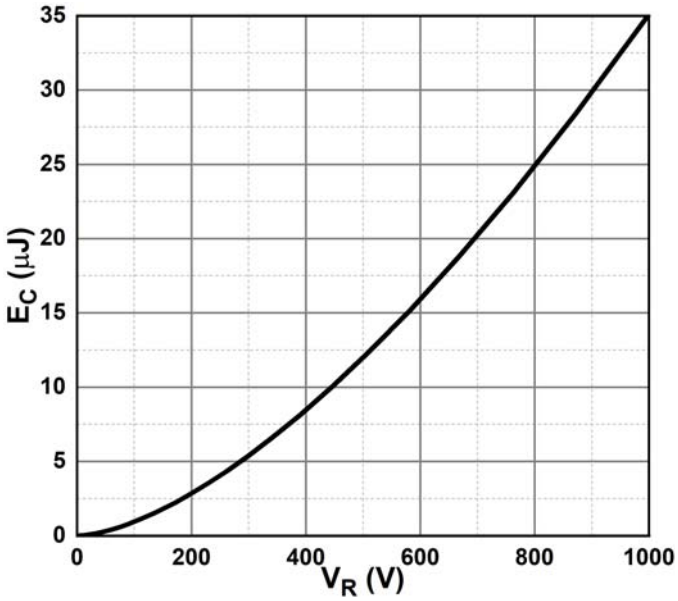


Figure 5. Capacitance Stored Energy

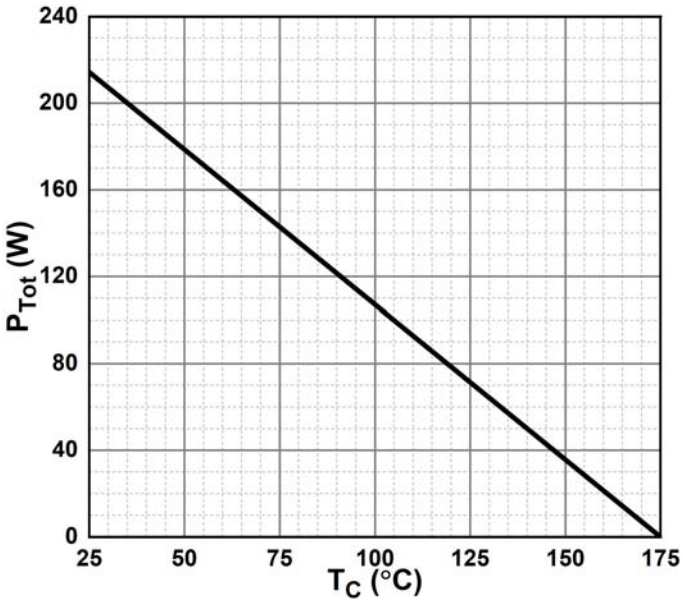


Figure 6. Power Derating

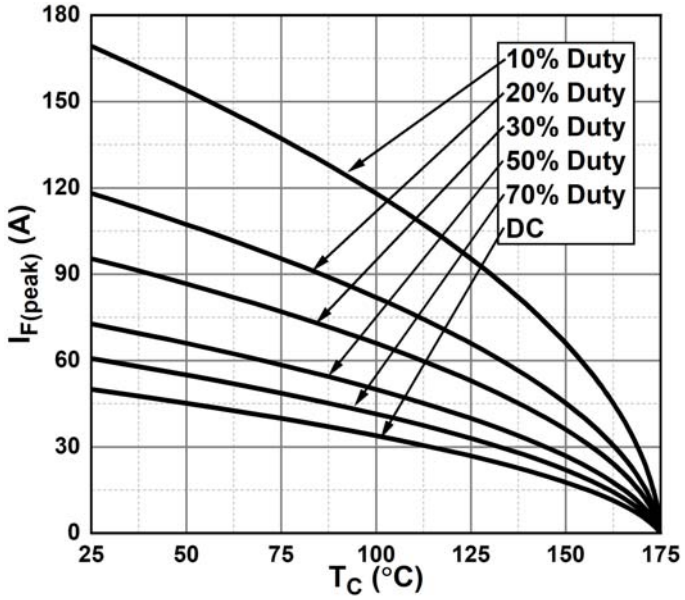


Figure 7. Current Derating

■Typical Characteristics (Device)

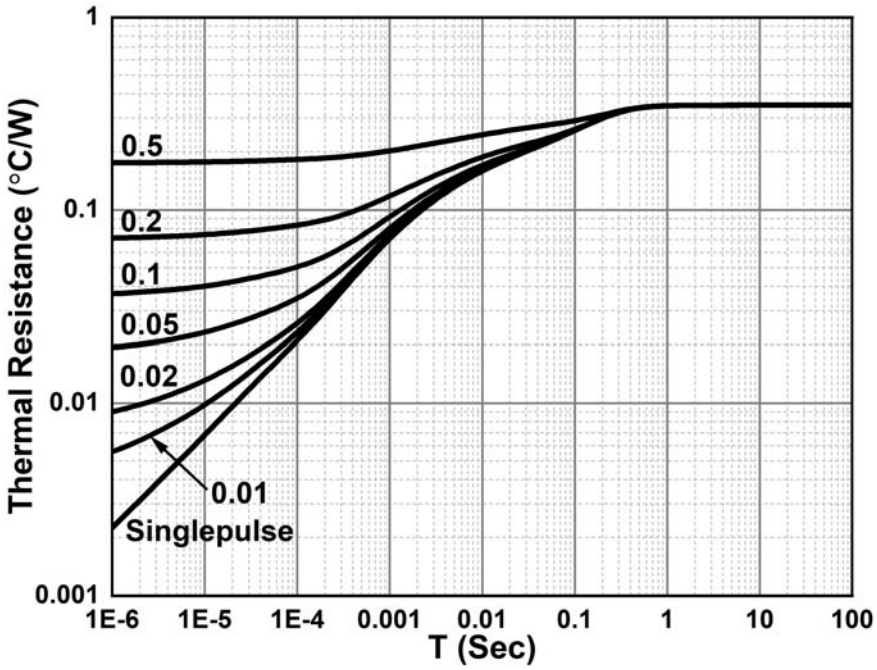
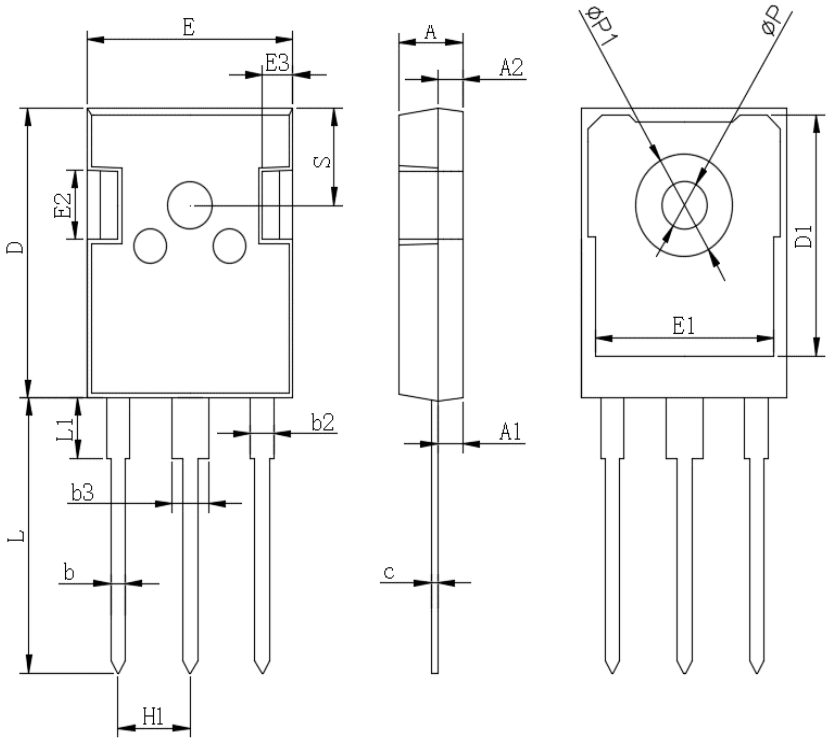


Figure 8. Transient Thermal Impedance

■Outline Dimensions

TO-247AB



TO-247AB		
Dim	Min	Max
A	4.80	5.20
A1	2.21	2.61
A2	1.85	2.15
b	1.0	1.4
b2	1.91	2.21
C	0.5	0.7
D	20.70	21.30
D1	16.25	16.85
E	15.50	16.10
E1	13.0	13.6
E2	4.80	5.20
E3	2.30	2.70
L	19.62	20.22
L1	-	4.30
ΦP	3.40	3.80
ΦP1	-	7.30
S	6.15TYP	
H1	5.44TYP	
b3	2.80	3.20

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